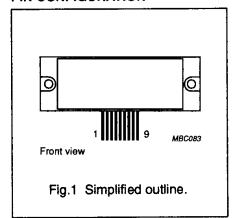
OM961/OM991

DESCRIPTION

The OM961 and OM991 are thin film hybrid integrated circuit hi-fi audio amplifiers for sinusoidal output power up to 60 W and 120 W respectively. The modules offer maximum design possibilities regarding amplification, ripple rejection, stability for complex loads etc. The amplifiers have built in short-circuit protection (SOAR protected) and are specially designed for low transient and harmonic distortion. All built in resistors are dynamically adjusted for optimum performance over a wide temperature range.

PIN CONFIGURATION



PINNING

| PIN | DESCRIPTION |
|-----|---------------------|
| 1 | supply (-) |
| 2 | ground |
| 3 | output |
| 4 | output |
| 5 | driver supply (-) |
| 6 | non inverting input |
| 7 | inverting input |
| 8 | boot strap |
| 9 | supply (+) |

QUICK REFERENCE DATA

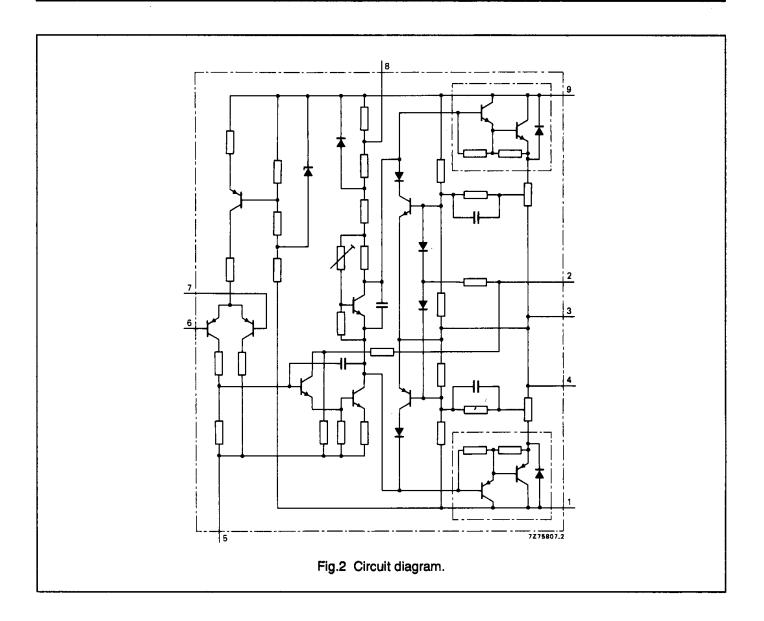
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | UNIT |
|------------------|----------------------------------|--|------|------|------|
| P _o | sinusoidal output power OM961 | $d_{tot} < 0.2\%;$ f = 20 Hz to 20 kHz; $R_L = 4 \Omega;$ $V_S = \pm 31 \text{ V}$ | 60 | - | W |
| | | $d_{tot} < 0.2\%;$ f = 20 Hz to 20 kHz; $R_L = 8 \Omega;$ $V_S = \pm 35 \text{ V}$ | 60 | _ | W |
| | sinusoidal output power OM991 | $d_{tot} < 0.2\%;$ f = 20 Hz to 20 kHz; $R_L = 4 \Omega;$ $V_S = \pm 45$ V | 60 | - | W |
| | | $d_{tot} < 0.2\%;$ f = 20 Hz to 20 kHz; $R_L = 8 \Omega;$ $V_S = \pm 50 \text{ V}$ | 60 | - | W |
| d _{tot} | total harmonic distortion | P _o = 1 W; f = 1 kHz | - | 0.02 | % |

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT |
|------------------|---|------|------|------|
| $\overline{v_s}$ | symmetrical supply voltage | | | |
| - | OM961 | - | ±45 | V |
| | OM991 | - | ±50 | V |
| T _{stg} | storage temperature range | -30 | 100 | °C |
| T _{mb} | mounting base operating temperature range | _ | 95 | °C |

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CHARACTERISTICS

Measured in circuit shown in Fig.3; $T_{mb} = 25$ °C.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|------------------|----------------------------------|---|------|------|------|------|
| V _s | symmetrical supply voltage | | | | | |
| | OM961 | | ±31 | - | ±35 | V |
| | OM991 | 22.2 | ±40 | _ | ±45 | V |
| tot | total supply current | zero signal | - | 100 | | mA |
| P _o | sinusoidal output power OM961 | $d_{tot} < 0.2\%;$ f = 20 Hz to 20 kHz; $R_L = 4 \Omega;$ note 1 note 2 | 60 | - | _ | W |
| | | $d_{tot} < 0.2\%;$ f = 20 Hz to 20 kHz; $R_L = 8 \Omega$ note 2 | - | - | 60 | W |
| | sinusoidal output power OM991 | $d_{tot} < 0.2\%;$ f = 20 Hz to 20 kHz; $R_L = 4 \Omega$ | 120 | - | _ | W |
| | | $d_{tot} < 0.2\%;$ f = 20 Hz to 20 kHz; $R_L = 8 \Omega$ | - | - | 90 | W |
| | clipping level | $d_{tot} = 0.7\%;$ f = 1 kHz; $R_L = 4 \Omega$ | | | | |
| | OM961 | | - | 75 | - | w |
| | OM991 | | 100 | _ | 135 | w |
| d _{tot} | total harmonic distortion | P _o = 1 W; f = 1 kHz | - | 0.02 | - | % |
| d _{im} | intermodulation distortion | $f_1 = 250 \text{ Hz};$ $f_2 = 8 \text{ kHz}$ amplitude ratio $V_{f1}/V_{f2} = 4/1$ | | | | |
| | | P _o = 1 W | - | 0.05 | - | % |
| | | P _o = rated value | - | 0.1 | - | % |
| V _i | input sensitivity | P _o = rated value | | | | |
| | OM961 | | 1 | - | 1.4 | V |
| | OM991 | | 1.4 | | 1.7 | V |
| R _i | input impedance | determined by input circuitry | _ | 10 | _ | kΩ |
| G _o | open loop gain | | - | 80 | T- | dB |

Notes

- 1. Federal trade commission U.S.A.
- 2. Po is stated as rated value.

OM961/OM991

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|------------------|--------------------------|---|------|------|-------|------|
| G _c | closed loop gain | | _ | 24 | 1- | dB |
| f | frequency response | P _o = rated value -10 dB (-1 dB) | 30 | - | 40000 | Hz |
| f _p | power bandwidth | –3 dB | 20 | - | 40000 | Hz |
| S/N | signal to noise ratio | wide band; P _o = 50 mW; unweighted | _ | 75 | _ | dB |
| | | A-curve; P _o = 50 mW; weighted | _ | 87 | _ | dB |
| V _{off} | DC output offset voltage | | _ | ±20 | _ | mV |
| RR | ripple rejection | | 65 | _ | - | dB |
| Z _o | output impedance | | - | 0.05 | - | Ω |

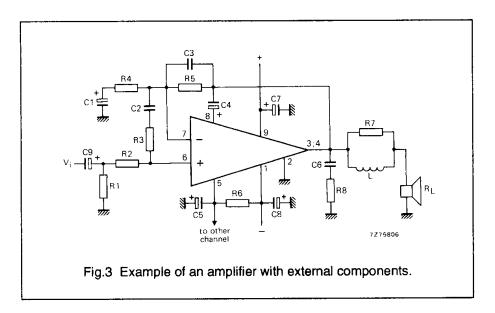
THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | NOM. | UNIT |
|----------------------|--------------------------------|-------------------------------------|------|------|
| R _{th h-a} | from heatsink to ambient | heatsink length a = 50 mm (note 1) | 1.0 | K/W |
| R _{th h-a} | from heatsink to ambient | heatsink length a = 75 mm (note 1) | 0.7 | K/W |
| R _{th h-a} | from heatsink to ambient | heatsink length a = 100 mm (note 1) | 0.6 | K/W |
| R _{th h-a} | from heatsink to ambient | heatsink length a = 150 mm (note 1) | 0.4 | K/W |
| R _{th mb-h} | from mounting base to heatsink | using heatsink compound | 0.2 | K/W |

Note

1. See Fig.5

OM961/OM991



List of components

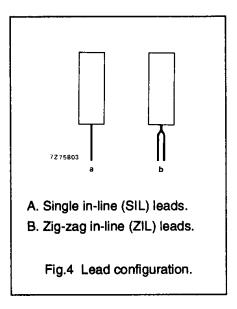
Philips Semiconductors

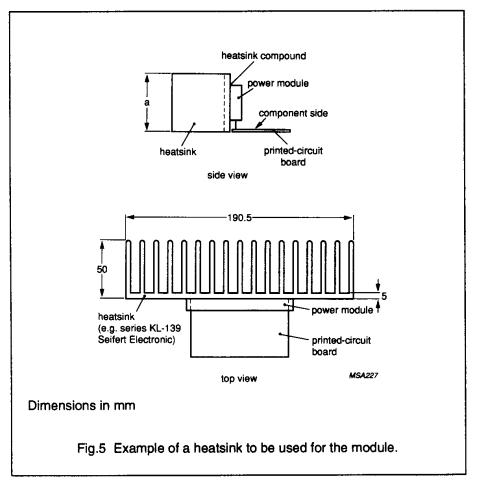
| COMPONENT | DESCRIPTION | VALUE |
|----------------|-----------------|----------|
| R1 | 0.25 W resistor | 10 kΩ |
| R2 | 0.25 W resistor | 4.7 kΩ |
| R3 | 0.25 W resistor | 300 Ω |
| R4 | 0.25 W resistor | 680 Ω |
| R5 | 0.25 W resistor | 10 kΩ |
| R6 | 0.5 W resistor | 22 Ω |
| R7 | 0.25 W resistor | 2.2 Ω |
| R8 | 0.5 W resistor | 10 Ω |
| C1 | 10 V capacitor | 47 μF |
| C2 | capacitor (10%) | 270 pF |
| C3 | capacitor (10%) | 120 pF |
| C4 | 100 V capacitor | 100 μF |
| C5 | 63 V capacitor | 470 μF |
| C6 | 100 V capacitor | 100 nF |
| C7 | 63 V capacitor | 10 μF |
| C8 | 63 V capacitor | 10 μF |
| C9 | 63 V capacitor | 1 μF |
| L | inductor | 4 μΗ |
| R _L | load resistance | 4 or 8 Ω |

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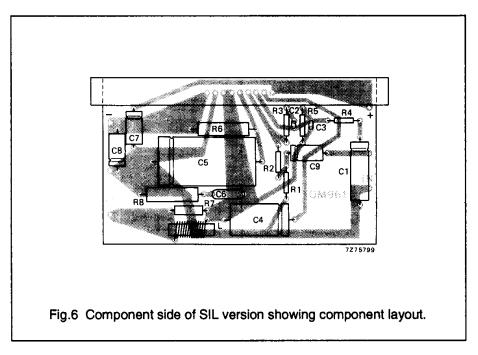
MOUNTING RECOMMENDATIONS

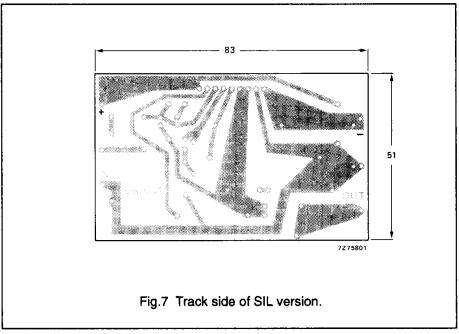
The modules are delivered with SIL (single in-line) leads but may also be bent to ZIL (zig-zag in-line) configuration.



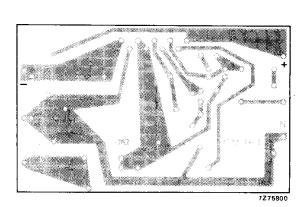


OM961/OM991



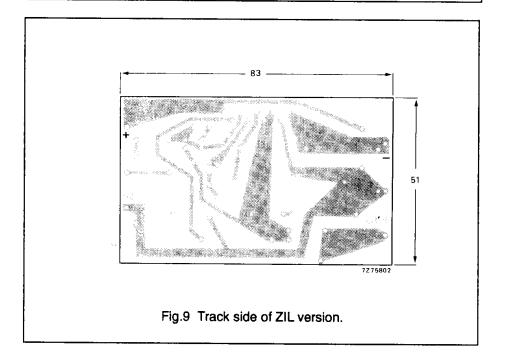


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For component layout see Fig.6.

Fig.8 Component side of ZIL version.



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PACKAGE OUTLINE

